TOSHIBA Photocoupler Photorelay

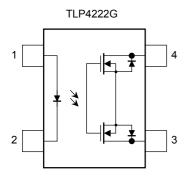
TLP4222G,TLP4222G-2

Telecommunication
Measurement Equipment
Security Equipment
FA

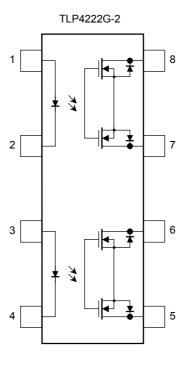
The Toshiba TLP4222G consists of an aluminum gallium arsenide infrared emitting diode optically coupled to a photo-MOSFET and is the normally closed photorelay with 350-V withstanding voltage.

- · Normally closed device
- Peak off-state voltage: 350 V (min)
- Trigger LED current: 3 mA (max)
- On-state current: 100 mA (max)
- On-state resistance: 50Ω (max)
- Isolation voltage: 2500 Vrms (min)

Pin Configuration (top view)



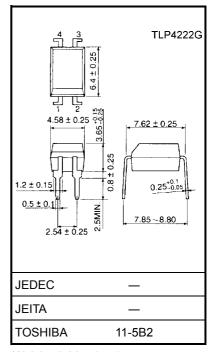
- 1: Anode
- 2: Cathode
- 3: Drain
- 4: Drain



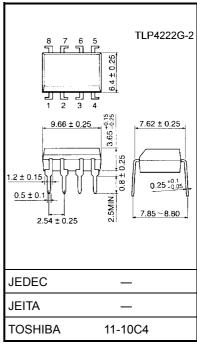
- 1, 3 : Anode
- 2, 4 : Cathode
- 5 : Drain D1
- 6 : Drain D2
- 0 . Diaiii D2
- 7 : Drain D3
- 8 : Drain D4

1

Unit: mm



Weight: 0.26 g (typ.)



Weight: 0.54 g (typ.)



Maximum Ratings (Ta = 25°C)

	Cha	Symbol	Rating	Unit		
	Forward current			l _F	50	mA
	Forward current derating (Ta	ΔI _F /°C	-0.5	mA/°C		
LED	Peak forward current (100 μs	pulse, 100 pps)		I _{FP}	1	Α
	Reverse voltage	V _R	5	V		
	Junction temperature		Tj	125	°C	
	Off-state output terminal voltage	V _{OFF}	350	V		
	On-state current	TLP4222G				
		TLP4222G-2	One channel operation	I _{ON}	100	mA
Detector		1LP4222G-2	Two channel operations			
Dete	On-state current derating (Ta ≧ 25°C)	TLP4222G				
		TLP4222G-2	One channel operation	∆l _{ON} /°C	-1.0	mA/°C
		1LF4222G-2	Two channel operations			
	Junction temperature		Tj	125	°C	
Stora	age temperature range	T _{stg}	-55 to 125	°C		
Ope	rating temperature range	T _{opr}	-40 to 85	°C		
Lead	d soldering temperature (10 s)	T _{sol}	260	°C		
Isola	Isolation voltage (AC, 1 min, R.H. \leq 60%) (Note 1)				2500	Vrms

Note 1: For TLP4222G, Pins 1 and 2 are shorted together, and pins 3 and 4 are shorted together. For TLP4222G-2, Pins 1, 2, 3 and 4 are shorted together, and pins 5, 6, 7 and 8 are shorted together.

Recommended Operating Conditions

Characteristics	Symbol	Min	Тур.	Max	Unit
Supply voltage	V_{DD}	_	_	280	V
Forward current	lF	5	_	25	mA
On-state current	I _{ON}	_	_	100	mA
Operating temperature	T _{opr}	-20	_	65	°C

Electrical Characteristics (Ta = 25°C)

	Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
LED	Forward voltage	V _F	I _F = 10 mA	1.0	1.15	1.3	V
	Reverse current	I _R	V _R = 5 V	_	_	10	μА
	Capacitance	C _T	V = 0, f = 1 MHz	_	30	_	pF
ctor	Off-state current	l _{OFF}	V _{OFF} = 350 V, I _F = 5 mA	_	_	1	μА
Detector	Capacitance	C _{OFF}	V = 0, f = 1 MHz, I _F = 5 mA	_	30	_	pF



Coupled Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FC}	I _{OFF} = 10 μA	_	1	3	mA
Return LED current	I _{FT}	I _{ON} = 100 mA	0.1	_	_	mA
On-state resistance	R _{ON}	I _{ON} = 100 mA		30	50	Ω

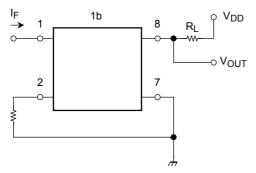
Isolation Characteristics (Ta = 25°C)

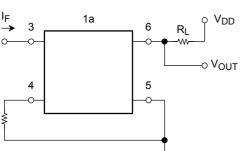
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	V _S = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≦ 60%	5×10^{10}	10 ¹⁴	_	Ω
	-	AC, 1 min	2500	_	_	Vrms
Isolation voltage		AC, 1 s, in oil	_	5000	_	VIIIIS
		DC, 1 min, in oil	—	5000	_	Vdc

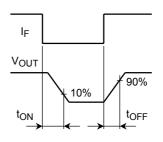
Switching Characteristics (Ta = 25°C)

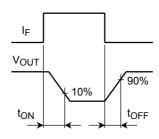
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Turn-on time	t _{ON}	$R_L = 200 \Omega$	_	0.25	0.5	ms
Turn-off time	t _{OFF}	$V_{DD} = 20 \text{ V, I}_F = 5 \text{ mA}$ (Note 2)	_	0.5	1	ms

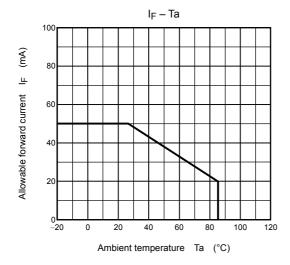
Note 2: Switching time test circuit

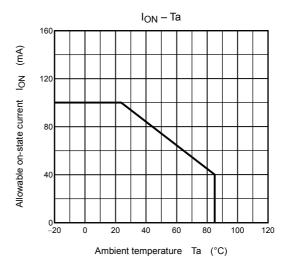


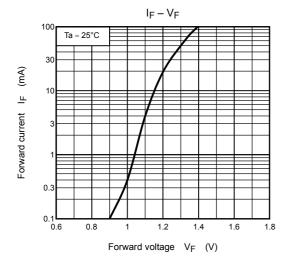


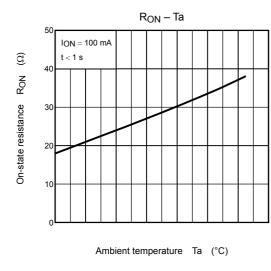


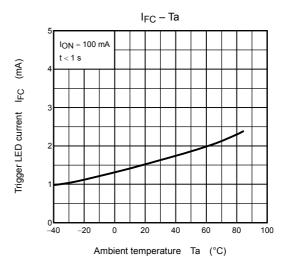


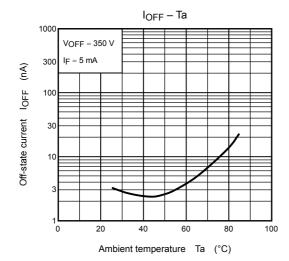


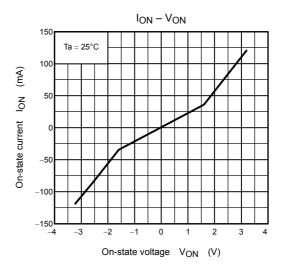


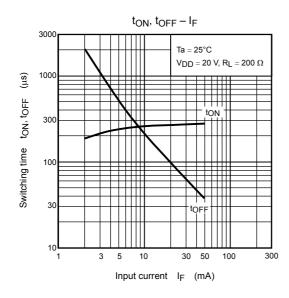


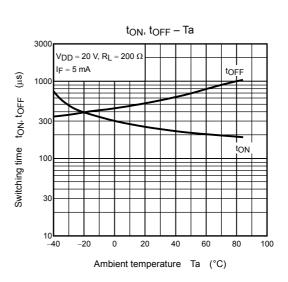












RESTRICTIONS ON PRODUCT USE

020704EBC

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property.
 In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- Gallium (GaAs) Arsenide is a substance used in the products described in this document. GaAs dust or vapor is harmful to the human body. Do not break, cut, crushu or dissolve chemically.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No
 responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other
 rights of the third parties which may result from its use. No license is granted by implication or otherwise under
 any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.